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- Operating Current Range
  - LM285 . . . 10  $\mu\text{A}$  to 20 mA
  - LM385 . . . 15  $\mu\text{A}$  to 20 mA
  - LM385B . . . 15  $\mu\text{A}$  to 20 mA
- 1% and 2% Initial Voltage Tolerance
- Reference Impedance
  - LM385...1 Ω Max at 25°C
  - All Devices . . . 1.5  $\Omega$  Max Over Full Temperature Range
- Very Low Power Consumption
- Applications:
  - Portable Meter References
  - Portable Test Instruments
  - Battery-Operated Systems
  - Current-Loop Instrumentation
  - Panel Meters
- Designed to be Interchangeable With National LM285-1.2 and LM385-1.2

#### description

D PACKAGE (TOP VIEW) 8 CATHODE NC 7 1 NC NCΠ 2 6 NC NC 3 ANODE 5 🛛 NC 4 LP PACKAGE (TOP VIEW) Ľ ANODE [] CATHODE Г٦ NC

NC-No internal connection

These micropower, two-terminal, band-gap voltage references operate over a 10-µA to 20-mA current range and feature exceptionally low dynamic impedance and good temperature stability. On-chip trimming provides tight voltage tolerance. The band-gap reference for these devices has low noise and long-term stability.

The design makes these devices exceptionally tolerant of capacitive loading and thus, easier to use in most reference applications. The wide dynamic operating temperature range accommodates varying current supplies with excellent regulation.

The extremely low power drain of this series makes them useful for micropower circuitry. These voltage references can be used to make portable meters, regulators, or general-purpose analog circuitry, with battery life approaching shelf life. The wide operating current range allows them to replace older references with tighter-tolerance parts.

The LM285-1.2 is characterized for operation from  $-40^{\circ}$ C to  $85^{\circ}$ C. The LM385-1.2 and LM385B-1.2 are characterized for operation from  $0^{\circ}$ C to  $70^{\circ}$ C.

AVAILABLE OPTIONS								
	¥-	PACKAGED D						
TA	TOLERANCE	SMALL OUTLINE (D)	PLASTIC (LP)	СПГРОКМ (Y)				
0°C to 70°C	2%	LM385D-1.2	LM385LP-1.2					
0010700	1%	LM385BD-1.2	LM385BLP-1.2	LM385Y-1.2				
-40°C to 85°C	1%	LM285D-1.2	LM285LP-1.2					

The D package is available taped and reeled. Add the suffix R to the device type (e.g., LM385DR-1-2). The chip form is tested at  $T_A = 25^{\circ}C$ .

<sup>†</sup> For ordering purposes, the decimal point in the part number must be replaced with a hyphen (i.e., show the -1.2 suffix as "-1-2").



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#### symbol



CATHODE

NOTE A: Component values shown are nominal.

### absolute maximum ratings over operating free-air temperature range<sup>†</sup>

ANODE -

Reverse current, I <sub>R</sub>	30 mA
	IU IIIA
Package thermal impedance, $\theta_{JA}$ (see Notes 1 and 2): D package	. 197°C/W
LP package	. 156°C/W
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	260°C
Storage temperature range, T <sub>stg</sub>	°C to 150°C

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. Maximum power dissipation is a function of  $T_{J(max)}$ ,  $\theta_{JA}$ , and  $T_A$ . The maximum allowable power dissipation at any allowable ambient temperature is  $P_D = (T_{J(max)} - T_A)/\theta_{JA}$ . Operation at the absolute maximum  $T_J$  of 150°C can impact reliability.

2. The package thermal impedance is calculated in accordance with JESD51, except for through-hole packages which use a trace length of zero.

#### recommended operating conditions

	MIN	MAX	UNIT	
Reference current, IZ		0.01	20	mA
	LM285-1.2	-40	85	°C
Operating nee-an temperature range, rA	LM385-1.2, LM385B-1.2	0	70	-0



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PARAMETER		TEST		LM285-1.2		LM385-1.2			LM385B-1.2			LINIT		
		CONDITIONS	'A'	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX		
VZ	Reference voltage	I <sub>Z</sub> = I(min) to 20 mA <sup>‡</sup>	25°C	1.223	1.235	1.247	1.21	1.235	1.26	1.223	1.235	1.247	V	
ανΖ	Average temperature coefficient of reference voltage§	IZ = I(min) to 20 mA‡	25°C		±20			±20			±20		ppm/°C	
	Change in reference voltage with current	$I_Z = I(min)$ to 1 mA <sup>‡</sup>	25°C			1			1			1		
			Full range			1.5			1.5			1.5	1 .	
ΔVZ		$I_Z = 1 mA$ to 20 mA	25°C			12			20			20	mv	
			Full range			30			30			30		
$\Delta V_Z / \Delta t$	Long-term change in reference voltage	IZ = 100 μA	25°C		±20			±20			±20		ppm/khr	
I <sub>Z</sub> (min)	Minimum reference current		Full range		8	10		8	15		8	15	μΑ	
_	Reference impedance	Reference $I_Z = 100 \ \mu A$ ,impedance $f = 25 \ Hz$	25°C		0.2	0.6		0.4	1		0.4	1	0	
ZZ			Full range			1.5			1.5			1.5	52	
Vn	Broadband noise voltage	I <sub>Z</sub> = 100 μA, f = 10 Hz to 10 kHz	25°C		60			60			60		μV	

#### electrical characteristics at specified free-air temperature

<sup>†</sup> Full range is –40°C to 85°C for the LM285-1.2, and 0°C to 70°C for the LM385-1.2 and LM385B-1.2.

 $\pm$  I(min) = 10 µA for the LM285-1.2 and 15 µA for the LM385-1.2 and LM385B-1.2.

\$ The average temperature coefficient of reference voltage is defined as the total change in reference voltage divided by the specified temperature range.

# electrical characteristics, $T_A = 25^{\circ}C$

DADAMETED		TEST CONDITIONS	LI	LINUT		
	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	
VZ	Reference voltage	I <sub>Z</sub> = 15 μA to 20 mA	1.21	1.235	1.26	V
αγΖ	Average temperature coefficient of reference voltage§	I <sub>Z</sub> = 15 μA to 20 mA		±20		ppm/°C
Δ٧Ζ	Change in reference veltage with ourrent	I <sub>Z</sub> = 15 μA to 1 mA	1		m)/	
	Change in reference voltage with current	$I_Z = 1 \text{ mA to } 20 \text{ mA}$			20	mv
$\Delta V_Z / \Delta t$	Long-term change in reference voltage	I <sub>Z</sub> = 100 μA		±20		ppm/khr
I <sub>Z</sub> (min)	Minimum reference current			8	15	μΑ
zz	Reference impedance	I <sub>Z</sub> = 100 μA		0.4	1	Ω
Vn	Broadband noise voltage	I <sub>Z</sub> = 100 μA, f = 10 Hz to 10 kHz		60		μV

§ The average temperature coefficient of reference voltage is defined as the total change in reference voltage divided by the specified temperature range.



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**TYPICAL CHARACTERISTICS<sup>†</sup>** 

<sup>†</sup> Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.



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### **TYPICAL CHARACTERISTICS<sup>†</sup>**

<sup>†</sup> Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.



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**APPLICATION INFORMATION** 

<sup>‡</sup> Adjust for 12.17 mV at 25°C across 412  $\Omega$ 





Figure 10. Operation Over a Wide Supply Range



Figure 11. Reference From a 9-V Battery



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